

Double Dirac cones and topologically nontrivial phonons for continuous square symmetric $C_{4(v)}$ and $C_{2(v)}$ unit cells

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Because phononic topological insulators have primarily been studied in discrete, graphenelike structures with $C_{6(v)}$ or $C_{3(v)}$ hexagonal symmetry, an open question is how to systematically achieve double Dirac cones and topologically nontrivial structures using continuous, nonhexagonal unit cells. Here, we address this challenge by presenting a computational methodology for the inverse design of continuous two-dimensional square phononic metamaterials exhibiting $C_{4(v)}$ and $C_{2(v)}$ symmetry. This leads to the systematic design of square unit cell topologies exhibiting a double Dirac degeneracy, which enables topologically protected interface propagation based on the quantum spin Hall effect (QSHE). Numerical simulations prove that helical edge states emerge at the interface between two topologically distinct square phononic metamaterials, which opens the possibility of QSHE-based pseudospin-dependent transport beyond hexagonal lattices.

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I. INTRODUCTION

The discovery of topological insulators (TIs) in quantum mechanical systems [1–6] has stimulated significant interest in developing topological analogs in other fields, including acoustics [7,8], photonics [9–11], and phononics [5,12,13]. TIs have attracted significant scientific interest primarily due to their potential to enable lossless propagation of wave energy along well-defined interfaces [14–16]. There are various approaches to obtaining topologically protected wave propagation, most of which are based on either the quantum hall effect (QHE) [1], the quantum spin hall effect (QSHE) [16], or the quantum valley hall effect (QVHE) [17]. Many reports on obtaining topologically protected wave propagation have emerged in recent years using these fundamental principles [5,8,12,13,15,18–35].

A commonality to nearly all studies on phononic TIs is their dependence on using graphenelike discrete, hexagonally symmetric (i.e., C_6 or C_3) lattice structures to obtain double Dirac cones as the first step to achieving topologically nontrivial structures. While the usage of hexagonal symmetries is well established, this limits the design space for TIs, and fundamental questions regarding the structure and resulting topological properties of different structural symmetries remain unresolved. Because of this, researchers have recently investigated the possibility of achieving Dirac cones in nonhexagonal lattices [36–42]. However, the challenge remains to create continuous unit cells that do not rely on hexagonal symmetry in order to exhibit a double Dirac cone, while also forming the basis for spin-orbit coupling-based mode inversion, thus enabling QSHE-based topologically protected interfacial wave propagation.

In this article, we address this challenge by presenting a multiobjective gradient-based topology optimization approach that enables, in contrast to previous topology optimization methods for TIs [33,43,44], the ability to design continuous, square symmetric unit cells that serve as the building blocks for phononic TIs. We utilize the design procedure to obtain a double Dirac cone using antiplane shear waves in an elastic square lattice, and show that breaking symmetry of the resulting square topology leads to a topologically nontrivial band gap and pseudospin-dependent wave propagation. Furthermore, we show that the proposed design methodology matches the eigensystem properties of the Bernevig-Hughes-Zhang (BHZ) [45] effective Hamiltonians we derived for square symmetric unit cells. Therefore, this work opens the possibility of QSHE-based pseudospin-dependent transport beyond hexagonal lattices.

II. TOPOLOGY OPTIMIZATION APPROACH

A. Double Dirac cone

Our approach is a three-stage design strategy to match the eigensystem properties of the BHZ effective Hamiltonian [45] for the QSHE, in which the frequency of the double Dirac degeneracy and the width of the topological band gap are user-specified values. We first search for square lattices with a fourfold (double) Dirac degeneracy, as illustrated by the C_{4v} unit cell in Fig. 1(a). Next, we lift the quadruple degeneracy to open a complete band gap as in Fig. 1(b). Finally, we induce mode inversion as in Fig. 1(c) such that the interface of the two unit cells in Figs. 1(b) and 1(c) supports topologically protected wave propagation.

Each design stage leading to the continuous elastic square unit cells brings unique challenges, which we address through different objective functions governing the topology optimization. In the first stage when obtaining the double Dirac degeneracy, Herring's rule [46] on irreducible representations

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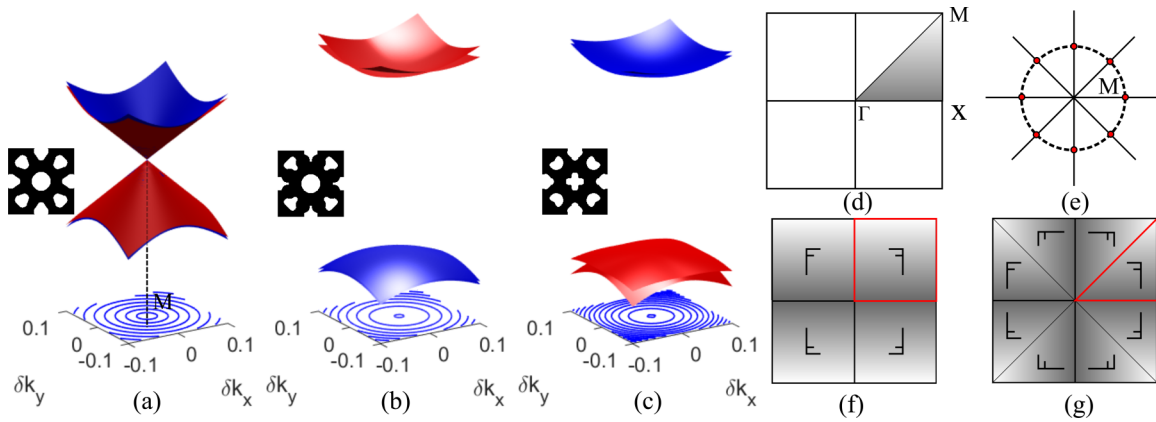


FIG. 1. Optimized C_{4v} unit cells with (a) Double Dirac cones, (b) complete band gap, (c) spin-orbit coupling-induced mode inversion, which is implied by the inverted surface colors with respect to (b). The eigenvalue surfaces are calculated using the finite element method around the high-symmetry point M and are colored in red and blue, which stand for different mode symmetries. The square lattice consists of 120×120 pixels, where each pixel stands for aluminum (black) or void (white). The equipfrequency contours correspond to the eigenvalue surfaces colored in blue. (d) First Brillouin zone of a square unit cell. The irreducible Brillouin zone is shaded in gray. (e) Frequency constraint points around M . Illustration of (f) C_{2v} and (g) C_{4v} symmetry. The minimal design region is enclosed by red line segments.

specifies that in hexagonal unit cells with C_{6v} symmetry, the double Dirac degeneracy consists of two deterministic degeneracies, which can easily be brought together to create the double degeneracy [18]. In contrast, the double Dirac degeneracy for C_{4v} and C_4 symmetries consists of mixed accidental and deterministic degeneracies, while the double Dirac degeneracy for C_{2v} and C_2 symmetries can only consist of accidental degeneracies. Because it is nontrivial to induce double Dirac degeneracies between deterministic and accidental, or two accidental, degeneracies, we leverage topology optimization to accomplish this via the first set of objective functions to a design frequency ω_0 ,

$$h = |\omega_0 - \omega(\mathbf{k}_0)_i|, \quad (1)$$

where $\omega(\mathbf{k}_0)_i$ is the frequency of the i th band at the high-symmetry point \mathbf{k}_0 , or the M point in our approach.

B. Mode matching during band-gap opening

A further challenge when creating spin-degenerate structures as in Figs. 1(a)–1(c) is to enforce the coalescence of eigenvalue surfaces that is inherent in the BHZ model. While relatively simple for hexagonal lattices, it is nontrivial for square lattices at the high-symmetry points of the irreducible Brillouin zone [39,41,42], where failure to match the eigenvalue surfaces along with the resulting small and anisotropic group velocities leads to significant loss along the topological interface [33,44,47]. To overcome this challenge, we assign eight frequency constraint points along the high-symmetry axis as in Fig. 1(e), forming a circle which encloses the high-symmetry (M) point of interest. This design objective constrains the equipfrequency contours to be circular as in Figs. 1(a)–1(c), while satisfying that the eigenvalues of the BHZ Hamiltonian depend upon the distance away from the degeneracy, $|\delta k|$. The frequency constraints bring the maximum and minimum frequencies along the circle for each of the two phonon bands that will be degenerate above and below the design frequency ω_0 to the same frequency value. The reason for this is twofold: it results in matching not only of

the eigenvalue surfaces, as shown in Fig. 1(a) and the surfaces colored in blue in Figs. 1(b) and 1(c), but also isotropy and matching of the group velocity near the high-symmetry (M) point, which is required in QSHE-based TIs [18].

For the eigenvalue surfaces that are colored in red in Figs. 1(b) and 1(c), some band splitting along Γ - M is inevitable due to the compatibility relations between different symmetries [48]. The frequency constraint points in this case serve to minimize the splitting between the branches. Numerical experiments have shown that these frequency constraints can be satisfied by the sixth to ninth bands at the M point. These frequency constraints can also be written as objective functions which minimize the aforementioned frequency differences as

$$h = |\max_l \{\omega(\mathbf{k} + \Delta \mathbf{k}_l)_i\} - \min_l \{\omega(\mathbf{k} + \Delta \mathbf{k}_l)_i\}|, \quad (2)$$

$$h = |\max_l \{\omega(\mathbf{k} + \Delta \mathbf{k}_l)_{i_2}\} - \min_l \{\omega(\mathbf{k} + \Delta \mathbf{k}_l)_{i_1}\}|, \quad (3)$$

$$h = |\max_l \{\omega(\mathbf{k} + \Delta \mathbf{k}_l)_{\bar{i}_2}\} - \min_l \{\omega(\mathbf{k} + \Delta \mathbf{k}_l)_{\bar{i}_1}\}|, \quad (4)$$

$$l = 1, \dots, 8.$$

Equation (2) concerns the isotropy of the dispersion relation of the four modes involved. For the i th band, eigenvalues are calculated along a small circle of radius $|\Delta \mathbf{k}_l| = 0.1|\Gamma X|$ centered at \mathbf{k} . We let l denote the eight points along the smaller circle shown in Fig. 1(e). The absolute values of the differences between the maximal and minimal frequencies on this circle are then optimized, such that the equipfrequency contours of the cones become circular. With Eqs. (1) and (2), we will have two circular double cones centered at \mathbf{k} with coalescing Dirac frequency ω_0 . However, it is shown in Fig. 2 that the slopes of the two double cones are not guaranteed to match. To resolve this, we introduce Eqs. (3) and (4). Equation (3) considers the two branches, marked by subscripts i_1 and i_2 , below the Dirac frequency. Here, we assume that the band index i_2 is larger than i_1 . We find the maximum frequency along the circle of branch i_2 and minimum frequency along the circle of branch i_1 and optimize the difference. When the

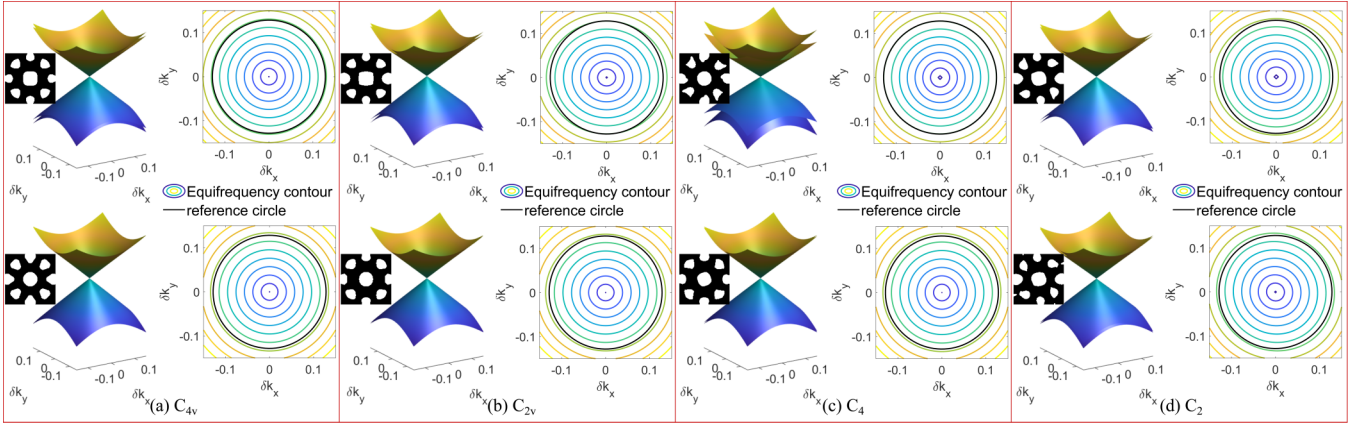


FIG. 2. Eigenvalue surfaces and equipfrequency contours of optimized unit cells with (a) C_{4v} symmetry, (b) C_{2v} symmetry, (c) C_4 symmetry, and (d) C_2 symmetry. The upper panel in each subfigure results from the optimization where the frequency constraints around M are not invoked, and the lower panel results from the optimization where the frequency constraints around M are invoked. The eigenvalue surfaces and contours are calculated using the $k \cdot p$ method.

vertices of the cone are fixed at ω_0 and the dispersion relation is approximately linear in the vicinity of \mathbf{k} , Eq. (3) essentially minimizes the differences between the two conical surfaces. Equation (4) acts upon the two branches above the Dirac frequency that is marked by subscripts \tilde{i}_1 and \tilde{i}_2 , where $\tilde{i}_2 > \tilde{i}_1$, for the purpose of eigenvalue surface matching. The above set of objective functions is also invoked during the second and third stage of optimization, again to ensure coalescence of the eigenvalue surfaces at the top and bottom edges of the topological band gap.

To see the effectiveness of the frequency constraints around M , we compare the results with a new set of unit cells of different symmetries with double Dirac cones which are generated by dropping the constraints. As shown in the upper panels of Fig. 2, which are optimization results when Eqs. (2)–(4) are not invoked, all the eigenvalue surfaces show splitting. The equipfrequency contours for C_{4v} and C_4 unit cells are circular, and the ones for C_{2v} and C_2 unit cells are elliptic. In contrast, as shown in the lower panels of Fig. 2, the coalescence of the eigenvalue surfaces is realized when the frequency constraints around M are invoked. The roundness of the equipfrequency contour is also improved for C_{2v} and C_2 unit cells.

Another issue to resolve emerges when opening a topologically nontrivial band gap from the initial quadruple degeneracy. Specifically, in a square lattice where spin states may potentially be formed entirely or in part by accidental degeneracies, a risk that arises in opening a band gap from the double Dirac degeneracy is the corresponding lifting of the accidental degeneracy. To ensure that the accidental degeneracy remains after the band gap is opened, we assign two degenerate frequencies, one below ($\underline{\omega}_0$) and the other above ($\tilde{\omega}_0$) the user-defined topological band gap. Therefore, the corresponding objective functions for the corresponding i th mode become

$$h = |\underline{\omega}_0 - \omega(\mathbf{k}_0)_i|; \quad i = \underline{i}_1, \underline{i}_2, \quad (5)$$

$$h = |\tilde{\omega}_0 - \omega(\mathbf{k}_0)_i|; \quad i = \tilde{i}_1, \tilde{i}_2, \quad (6)$$

which, in conjunction with the frequency constraints around M , results in structures and band gaps as in Fig. 1(b).

C. Mode inversion

Once the topology that has a band gap with two sets of degenerate modes at the top (modes \tilde{i}) and bottom (modes \underline{i}) of the band gap is obtained, the resulting mode shapes of the degenerate modes are used as the reference modes for the subsequent mode inversion step, which mimics strong spin-orbit coupling (SOC) [18]. The quality of mode inversion is measured by the square of normalized inner product of the displacement field, also known as the modal assurance criterion (MAC) [49]

$$\gamma_{i,j} = \frac{\langle U_i^0 | U_j \rangle^2}{\|U_i^0\|^2 \|U_j\|^2}, \quad (7)$$

where U_i^0 denotes the i th reference displacement mode, and U_j denotes the j th displacement mode in the unit cell with mode inversion. The value of $\gamma_{i,j}$ varies between zero and 1 such that when $\gamma_{i,j}$ is equal to 1, the mode shapes of U_i^0 and U_j are the same.

The optimization process to achieve mode inversion includes two steps. It starts from the four degenerate modes j in the double Dirac degeneracy as in Fig. 1(a), where we identify \underline{j} and \tilde{j} by searching for $\max\{\gamma_{i,j}\}$ given \underline{i} and \tilde{i} , respectively. $\max\{\gamma_{i,j}\}$ between the corresponding modes is then maximized to improve the inversion quality. Simultaneously, the frequency differences between $\underline{\omega}_0$ and $\omega(\mathbf{k}_0)_{\tilde{j}}$ and $\tilde{\omega}_0$ and $\omega(\mathbf{k}_0)_{\underline{j}}$ are minimized to induce mode inversion by bringing modes \tilde{j} to the lower edge of the band gap, and modes \underline{j} to the upper edge of the band gap. This mode inversion process is achieved through the following objective functions:

$$f = -\max\{\gamma_{i,j}\}; \quad i = \underline{i}_1, \underline{i}_2, \tilde{i}_1, \tilde{i}_2, \quad (8)$$

$$j = \underline{j}_1, \underline{j}_2, \tilde{j}_1, \tilde{j}_2, \quad (9)$$

$$h = |\underline{\omega}_0 - \omega(\mathbf{k}_0)_{\tilde{j}}|, \quad \tilde{j} = \tilde{j}_1, \tilde{j}_2, \quad (9)$$

$$h = |\tilde{\omega}_0 - \omega(\mathbf{k}_0)_{\underline{j}}|, \quad \underline{j} = \underline{j}_1, \underline{j}_2, \quad (10)$$

which leads to structures and band gaps as in Fig. 1(c). We emphasize that we do not need to explicitly prescribe symmetry breaking to mimic SOC in order to successfully complete this stage of the optimization process.

The multiobjective optimization problem including frequency constraints around M can be written as

$$\begin{aligned} \min_{x_e} \quad & \sum_p \alpha_p f_p(x_e) + \sum_q \beta_q h_q(x_e) \\ \text{Subject to} \quad & \mathbf{K}(\mathbf{k})\mathbf{U} = \omega^2 \mathbf{M}\mathbf{U}, \\ & x_e \in [0, 1], \end{aligned} \quad (11)$$

where p and q are indices representing objective functions involving eigenvectors and eigenvalues, respectively, α_p and β_q are weights, \mathbf{K} is the stiffness matrix, and \mathbf{M} is the mass matrix. $f_p(x_e)$, which is a function of relative density x_e , is only invoked when mode inversion is considered at the third stage of optimization. Equation (11) is solved deterministically by the gradient based optimizer method of moving asymptotes [50]. The design sensitivities of the objective functions are calculated using adjoint analysis, with special treatment for repeated eigenvalues and their corresponding eigenvectors [51]. The material properties are interpolated using solid isotropic material with penalization [52]. The minimum features of the design are controlled by a filter based on a Helmholtz-type partial differential equation where the final design which is free of partial density elements is obtained through Heaviside projection [53]. For the C_{2v} and C_{4v} symmetries we focus on here, the minimal design region is specified in Figs. 1(f) and 1(g), with the full unit cells reconstructed through the illustrated symmetry operations. The unit cells are made of aluminum, with shear modulus $\mu = 25.556$ GPa and density $\rho = 2700$ kg/m³.

III. BHZ HAMILTONIANS FOR SQUARE UNIT CELLS

Before providing numerical examples illustrating the utility of the proposed topology optimization approach, we first demonstrate that the double Dirac cones, as well as the degenerate modes at the top and bottom of the topologically nontrivial band gap, match those expected from the BHZ model Hamiltonian [45] for the QSHE. In order to do so, we first need to obtain the BHZ Hamiltonians for square lattices, i.e., for C_2 , C_{2v} , C_4 , and C_{4v} symmetries. To do so, we first note that the BHZ Hamiltonian can be written in the form

$$\mathcal{H}(\mathbf{k}) = \begin{bmatrix} \mathcal{H}_+ & 0 \\ 0 & \mathcal{H}_- \end{bmatrix}, \quad (12)$$

where

$$\mathcal{H}_\pm = \begin{bmatrix} M + B\delta k^2 & A\delta k_\mp \\ A^*\delta k_\pm & -M - B\delta k^2 \end{bmatrix}. \quad (13)$$

The topological transition between trivial and nontrivial states depends on the behavior of parameters A , B , and M , which determine the strength of the first-order mode coupling, second-order mode coupling, and the gap size of the topological

band gap, respectively. For example, when the two pseudospin states are degenerate, M and B vanish, leading to the formation of double Dirac cones. When strong spin-orbit coupling is introduced to lift the fourfold degeneracy, a complete topological band gap is formed with inverted eigenmodes that appear above and below the band gap, while the eigenvalue and group velocity degeneracy are kept intact at the edges of the band gap. The above effective Hamiltonian can be derived from a second-order $k \cdot p$ perturbation [48,54]. Here, we derive the effective BHZ Hamiltonians for C_{4v} , C_4 , C_{2v} , and C_2 symmetry to show the necessity of our optimization steps as explained in the previous section to match the BHZ model.

The $k \cdot p$ perturbation method is established based on the fact that eigenvectors in the neighborhood of a degeneracy can be expressed as a linear combination of the eigenvectors of the degeneracy, i.e., $\mathbf{u}(\mathbf{k}') = e^{i\delta\mathbf{k}\cdot\mathbf{r}} \sum_{n=1}^N \psi_n \mathbf{u}_n(\mathbf{k})$, where N is the eigenvalue multiplicity. For a general three-dimensional phononic unit cell, we substitute this relation into the equilibrium equation, $\nabla \cdot [\mathbf{C} : \nabla^s \mathbf{u}(\mathbf{k})] = -E(\mathbf{k})\rho \mathbf{u}(\mathbf{k})$, and get

$$\sum_{n=1}^N \psi_n [E(\mathbf{k})\delta_{mn} + \delta\mathbf{k} \cdot \mathbf{p} + \delta\mathbf{k}\delta\mathbf{k} : \mathbf{q}] = E_m(\mathbf{k}')\psi_m, \quad (14)$$

where

$$\mathbf{p} = \langle \mathbf{u}_m | \mathbf{p} | \mathbf{u}_n \rangle = - \int i\mathbf{u}_m^* \cdot [\mathbf{C} : \nabla^s + \nabla \cdot (\mathbf{C} \cdot)] \mathbf{u}_n d\Omega, \quad (15)$$

$$\mathbf{q} = \int \mathbf{u}_m^* \cdot \mathbf{C} \cdot \mathbf{u}_n d\Omega. \quad (16)$$

Here, \mathbf{C} is the stiffness tensor and \mathbf{u} is orthonormalized such that $\int \rho \mathbf{u}_m^* \mathbf{u}_n = \delta_{mn}$. Therefore, the effective Hamiltonian can be written as

$$\mathcal{H} = \mathcal{H}_0 + \mathcal{H}', \quad (17)$$

where $\mathcal{H}_0 = E(\mathbf{k})\delta_{mn} + \delta\mathbf{k}\delta\mathbf{k} : \mathbf{q}$ and the linear perturbation term $\mathcal{H}' = \delta\mathbf{k} \cdot \mathbf{p}$. $\delta\mathbf{k}$ is the incremental wave number away from the degenerate point. Subsequently, we will drop the δ symbol for simplicity. For the antiplane shear wave motion we consider here, the m th displacement mode only contains the out-of-plane component, denoted as u_m , and the stiffness tensor is replaced by the shear modulus μ .

A. C_{4v} unit cells

For the double Dirac cones we consider here, \mathcal{H}_0 can be written as a diagonal matrix, and \mathcal{H}' can be simplified by checking the nonzero $\langle u_m | \mathbf{p} | u_n \rangle$ entries via symmetry analysis. For C_{4v} symmetry the four modes involved, \mathbf{u}_m , have the same symmetry as $[p_x, p_y, d_{x^2-y^2}, d_{xy}]$, respectively. The p -like modes transform as E irreducible representation, the $d_{x^2-y^2}$ -like modes transform as B_1 irreducible representation, the d_{xy} -like modes transform as B_2 irreducible representation, and that operator \mathbf{p} transforms as a vector corresponding to E irreducible representation. After checking the direct product of related irreducible representations, we find that the nonzero entries only appear in the off-diagonal blocks and the detailed

entries are

$$\mathcal{H}'_{mn} = \begin{bmatrix} 0 & 0 & \langle u_1 | k_x \mathbf{p}_x | u_3 \rangle & \langle u_1 | k_y \mathbf{p}_y | u_4 \rangle \\ 0 & 0 & \langle u_2 | k_y \mathbf{p}_y | u_3 \rangle & \langle u_2 | k_x \mathbf{p}_x | u_4 \rangle \\ \langle u_3 | k_x \mathbf{p}_x | u_1 \rangle & \langle u_3 | k_y \mathbf{p}_y | u_2 \rangle & 0 & 0 \\ \langle u_4 | k_y \mathbf{p}_y | u_1 \rangle & \langle u_4 | k_x \mathbf{p}_x | u_2 \rangle & 0 & 0 \end{bmatrix}. \quad (18)$$

Notice that there is a vanishing \mathbf{p}_x (\mathbf{p}_y) component of the operator \mathbf{p} in C_{4v} symmetry. Evaluation of Eq. (18) shows that \mathcal{H}'_{mn} in general has the following form:

$$\mathcal{H}'_{mn} = \begin{bmatrix} 0 & 0 & Ak_x & Bk_y \\ 0 & 0 & -Ak_y & Bk_x \\ A^*k_x & -A^*k_y & 0 & 0 \\ B^*k_y & B^*k_x & 0 & 0 \end{bmatrix}, \quad (19)$$

where A and B are purely imaginary according to Eq. (15). Rewriting Eq. (19) on the new basis $[u_1 + iu_2, u_3 + iu_4, u_1 - iu_2, u_3 - iu_4]$ with $k_{\pm} = k_x \pm ik_y$, we have

$$\mathcal{H}'_{mn} = \begin{bmatrix} 0 & \frac{(A+B)k_-}{2} & 0 & \frac{(A-B)k_-}{2} \\ \frac{(A^*+B^*)k_+}{2} & 0 & \frac{(A^*-B^*)k_-}{2} & 0 \\ 0 & \frac{(A-B)k_+}{2} & 0 & \frac{(A+B)k_+}{2} \\ \frac{(A^*-B^*)k_+}{2} & 0 & \frac{(A^*+B^*)k_-}{2} & 0 \end{bmatrix}. \quad (20)$$

Equation (20) gives two sets of eigenvalues $\pm A|\mathbf{k}|$ and $\pm B|\mathbf{k}|$, which describe double Dirac cones with unmatched eigenvalue surfaces. However, the BHZ model demands that the eigenvalue surfaces should also match, essentially, $A = B$. It, therefore, necessitates the topology optimization step described in Sec. II B which seeks to minimize the eigensurface difference such that the effective Hamiltonian will take the following block-diagonal form:

$$\mathcal{H}'_{mn} = \begin{bmatrix} 0 & Ak_- & 0 & 0 \\ A^*k_+ & 0 & 0 & 0 \\ 0 & 0 & 0 & Ak_+ \\ 0 & 0 & A^*k_- & 0 \end{bmatrix}. \quad (21)$$

When a topological band gap is opened, the above effective Hamiltonian will no longer be adequate in describing the system, because now it must involve second-order perturbation to lift the degeneracy, where the formulation is given by [48]

$$\mathcal{H}'_{mn} \rightarrow \mathcal{H}'_{mn} + \sum_{\alpha} \frac{\mathcal{H}'_{m\alpha} \mathcal{H}'_{\alpha n}}{E_m - E_{\alpha}}, \quad (22)$$

where α labels the degenerate mode on the other edge of the gap opposite to the m th mode. The two sets of degenerate eigenvalues are given as $[E_p, E_p, E_d, E_d]$ for their p - and d -like modes. Due to the unbroken C_{4v} symmetry during the optimizations, components of $\mathcal{H}'_{m\alpha}$ and $\mathcal{H}'_{\alpha n}$ of the optimized unit cells have the same form as in Eqs. (18) and (19). The effective Hamiltonian for the general C_{4v} case can now be written as

$$\begin{bmatrix} E_p + \frac{|A|^2 k_x^2 + |B|^2 k_y^2}{E_p - E_d} & -\frac{|A|^2 - |B|^2}{E_p - E_d} k_x k_y & Ak_x & Bk_y \\ -\frac{|A|^2 - |B|^2}{E_p - E_d} k_x k_y & E_p + \frac{|A|^2 k_y^2 + |B|^2 k_x^2}{E_p - E_d} & -Ak_y & Bk_x \\ A^*k_x & -A^*k_y & E_d - \frac{|A|^2 (k_x^2 + k_y^2)}{E_p - E_d} & 0 \\ B^*k_y & B^*k_x & 0 & E_d - \frac{|B|^2 (k_x^2 + k_y^2)}{E_p - E_d} \end{bmatrix}. \quad (23)$$

Rewriting Eq. (23) using the pseudospin states as the new basis $[u_1 + iu_2, u_3 + iu_4, u_1 - iu_2, u_3 - iu_4]$, we have

$$\begin{bmatrix} E_p + \frac{(|A|^2 + |B|^2)k^2}{2(E_p - E_d)} & \frac{(A + B)k_-}{2} & \frac{(|A|^2 - |B|^2)k_-^2}{2(E_p - E_d)} & \frac{(A - B)k_-}{2} \\ \frac{(A^* + B^*)k_+}{2} & E_d - \frac{(|A|^2 + |B|^2)k^2}{2(E_p - E_d)} & \frac{(A^* - B^*)k_-}{2} & -\frac{(|A|^2 - |B|^2)k^2}{2(E_p - E_d)} \\ \frac{(|A|^2 - |B|^2)k_+^2}{2(E_p - E_d)} & \frac{(A - B)k_+}{2} & E_p + \frac{(|A|^2 + |B|^2)k^2}{2(E_p - E_d)} & \frac{(A + B)k_+}{2} \\ \frac{(A^* - B^*)k_+}{2} & -\frac{|A|^2 - |B|^2)k^2}{2(E_p - E_d)} & \frac{(A^* + B^*)k_-}{2} & E_d - \frac{(|A|^2 + |B|^2)k^2}{2(E_p - E_d)} \end{bmatrix}, \quad (24)$$

where $k_{\pm} = k_x \pm ik_y$. Observe that the matrix entries of Eq. (20) now appear at the same location in Eq. (24). Similar to Eq. (20), this effective Hamiltonian gives two sets of unmatched eigenvalue surfaces which are degenerate only at the high-symmetry (M) point mentioned earlier. This motivates our approach of leveraging topology optimization to minimize the frequency difference between eigenvalue surfaces in Sec. II B. For the BHZ Hamiltonian, this means that effectively $A = B$ and the Hamiltonian can be reduced to

$$\begin{bmatrix} E_p + \frac{|A|^2 k^2}{E_p - E_d} & Ak_- & 0 & 0 \\ A^* k_+ & E_d - \frac{|A|^2 k^2}{E_p - E_d} & 0 & 0 \\ 0 & 0 & E_p + \frac{|A|^2 k^2}{E_p - E_d} & Ak_+ \\ 0 & 0 & A^* k_- & E_d - \frac{|A|^2 k^2}{E_p - E_d} \end{bmatrix}. \quad (25)$$

Finally, we let $M = (E_p - E_d)/2$ and $B = |A|^2/(E_p - E_d) + D$, where D comes from the second-order term in \mathcal{H}_0 . This brings the effective Hamiltonian to the block-diagonal form as in Eqs. (12) and (13).

B. C_{2v} unit cells

For C_{2v} unit cells with double Dirac cones, symmetry analysis show that the effective Hamiltonian has the same form as Eq. (18), where there is vanishing operator components \mathbf{p}_x (\mathbf{p}_y). However, due to the lack of C_4 symmetry, \mathcal{H}'_{mn} has the following form:

$$\mathcal{H}'_{mn} = \begin{bmatrix} 0 & 0 & Ak_x & Bk_y \\ 0 & 0 & -Ck_y & Dk_x \\ A^* k_x & -C^* k_y & 0 & 0 \\ B^* k_y & D^* k_x & 0 & 0 \end{bmatrix}. \quad (26)$$

Again, Eq. (26) corresponds to two sets of unmatched eigenvalue surfaces. Furthermore, the group velocity is anisotropic due to the eigenvalues' dependence upon both k_x and k_y . This again motivates our topology optimization approach described in Sec. II B to effectively minimize the frequency differences between the eigenvalue surfaces. Within this analytic derivation, this implies that the effective Hamiltonian of the resultant unit cell will give $A = B = C = D$, and take the block-diagonal form as in Eq. (20). For the second-order perturbation, we substitute Eq. (26) into Eq. (22) and change basis from u_m to $[u_1 + iu_2, u_3 + iu_4, u_1 - iu_2, u_3 - iu_4]$ to get \mathcal{H}' . The block-diagonal form will hold when the eigenvalue surfaces are matched with $A = B = C = D$.

C. C_4 and C_2 unit cells

For C_4 and C_2 unit cells with double Dirac cones, there is no vanishing operator component of \mathbf{p} ; therefore,

$$\mathcal{H}'_{mn} = \begin{bmatrix} 0 & 0 & \langle u_1 | \mathbf{k} \cdot \mathbf{p} | u_3 \rangle & \langle u_1 | \mathbf{k} \cdot \mathbf{p} | u_4 \rangle \\ 0 & 0 & \langle u_2 | \mathbf{k} \cdot \mathbf{p} | u_3 \rangle & \langle u_2 | \mathbf{k} \cdot \mathbf{p} | u_4 \rangle \\ \langle u_3 | \mathbf{k} \cdot \mathbf{p} | u_1 \rangle & \langle u_3 | \mathbf{k} \cdot \mathbf{p} | u_2 \rangle & 0 & 0 \\ \langle u_4 | \mathbf{k} \cdot \mathbf{p} | u_1 \rangle & \langle u_4 | \mathbf{k} \cdot \mathbf{p} | u_2 \rangle & 0 & 0 \end{bmatrix}. \quad (27)$$

Specifically, for C_4 and C_2

$$\mathcal{H}'_{mn} = \begin{bmatrix} 0 & 0 & A_1 k_x - A_2 k_y & B_1 k_x + B_2 k_y \\ 0 & 0 & -A_2 k_x - A_1 k_y & B_2 k_x - B_1 k_y \\ A_1^* k_x - A_2^* k_y & -A_2^* k_x - A_1^* k_y & 0 & 0 \\ B_1^* k_x + B_2^* k_y & B_2^* k_x - B_1^* k_y & 0 & 0 \end{bmatrix}_{(C_4)}, \quad (28)$$

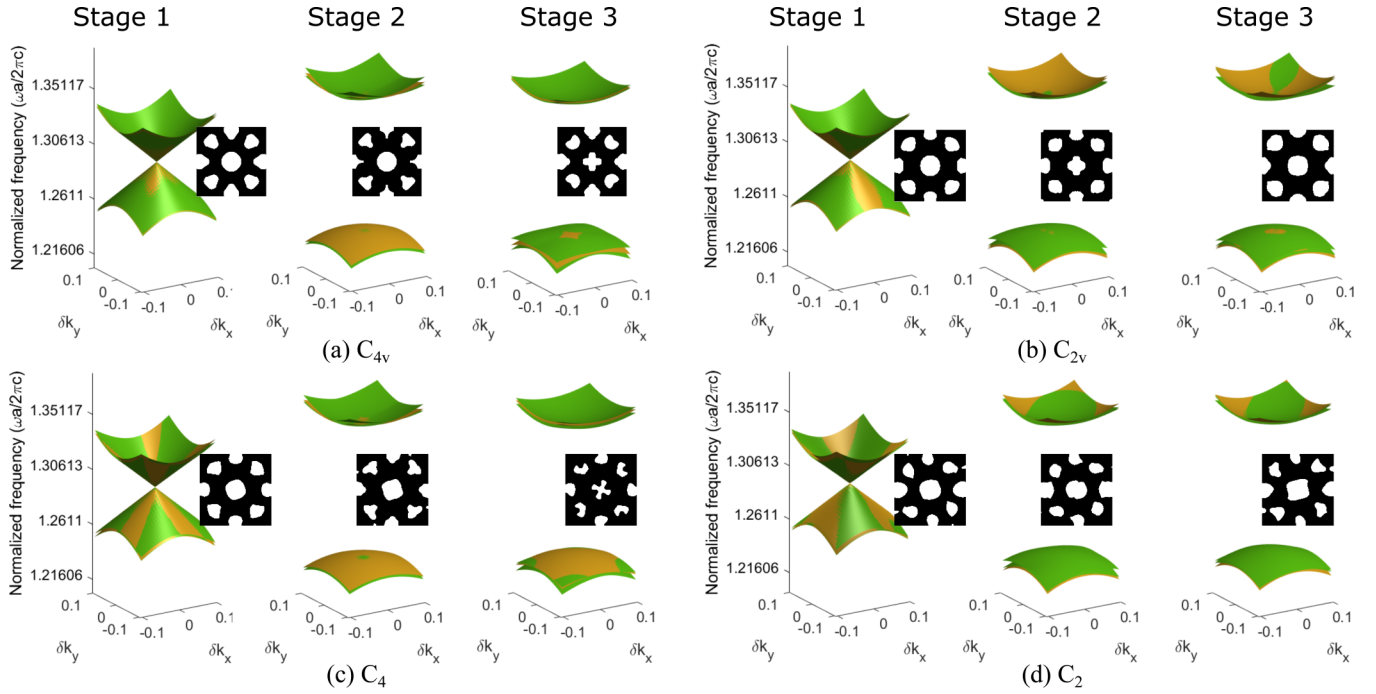


FIG. 3. Eigenvalue surfaces of optimized unit cells with (a) C_{4v} symmetry, (b) C_{2v} symmetry, (c) C_4 symmetry, and (d) C_2 symmetry. The surfaces which are calculated using FEM are colored in green, and the surfaces which are calculated using effective Hamiltonian are colored in yellow.

$$\mathcal{H}'_{mn} = \begin{bmatrix} 0 & 0 & A_1 k_x + A_2 k_y & -B_1 k_x + B_2 k_y \\ 0 & 0 & C_1 k_x - C_2 k_y & D_1 k_x + D_2 k_y \\ A_1^* k_x + A_2^* k_y & C_1^* k_x - C_2^* k_y & 0 & 0 \\ -B_1^* k_x + B_2^* k_y & D_1^* k_x + D_2^* k_y & 0 & 0 \end{bmatrix}_{(C_2)}. \quad (29)$$

For C_4 symmetry, the two sets of eigenvalues, $\pm V_{\pm}|\mathbf{k}|$, again describe double Dirac cones with unmatched eigenvalue surfaces. Since the eigenvalues only depend on $|\mathbf{k}|$, the group velocities are isotropic and given as

$$V_{\pm} = \frac{\sqrt{2(|A_1|^2 + |A_2|^2 + |B_1|^2 + |B_2|^2 \pm \Delta)}}{2},$$

$$\Delta = (|A_1|^2 + |A_2|^2)^2 + (|B_1|^2 + |B_2|^2)^2 - 4(A_1 A_2^* B_2 B_1^* + A_2 A_1^* B_1 B_2^*) + 2(|A_1|^2 |B_1|^2 + |A_2|^2 |B_2|^2 - |A_1|^2 |B_2|^2 - |A_2|^2 |B_1|^2). \quad (30)$$

For C_2 symmetry, the eigenvalues' dependence on both k_x and k_y leads to anisotropic group velocity, and the eigenvalue surfaces are also unmatched. We then substitute Eqs. (28) and (29) into Eq. (22) and change to the new basis to obtain the effective Hamiltonians under second-order perturbation for C_4 and C_2 , respectively. The block-diagonal form will hold when the eigenvalue surfaces are matched, while the anisotropy in group velocity is addressed by topology optimization as described in Sec. II B.

D. Comparison of optimization results with BHZ effective Hamiltonians

We show in Fig. 3 finite element method (FEM) calculations of the optimized C_{4v} , C_4 , C_{2v} , and C_2 unit cells and the eigenvalues from the above-derived perturbation theory.

Specifically, Fig. 3 shows that the effective Hamiltonians not only match the numerical results, but also successfully approximate the BHZ model due to the optimization of the frequency difference between the surfaces, as shown in Fig. 3. From the previous section, we can see that the difficulty in designing C_{4v} and C_4 symmetric cases lies in matching the eigenvalue surfaces, while for C_{2v} and C_2 symmetric cases, it lies in both the cancellation of anisotropy of group velocity and the matching of eigenvalue surfaces. Due to the fact that the minimal design domains for C_4 and C_{2v} symmetric cases are of the same size which occupies a quarter of the square lattice, these two cases have roughly the same design complexity for the optimizer when it searches for the optimal configuration in the feasible region. However, the minimal design domain for the C_2 symmetric case occupies one-half of the square lattice, which significantly increases the design

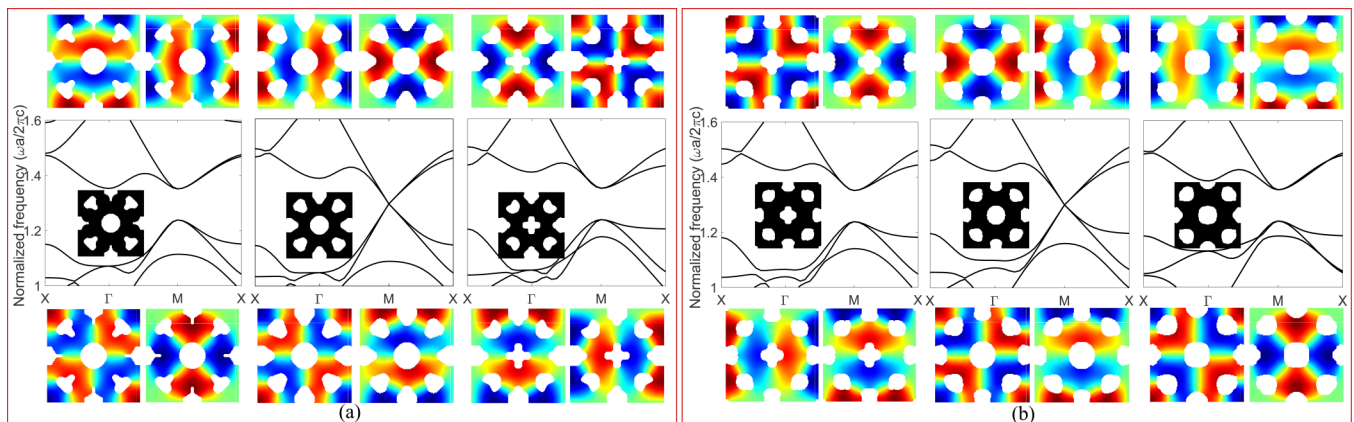


FIG. 4. (a) Optimized C_{4v} unit cells that exhibit double Dirac cones (middle), band-gap opening in the second stage of optimization (left), and mode inversion (right). (b) Optimized C_{2v} unit cells that exhibit double Dirac cones (middle), band-gap opening in the second stage of optimization (left), and mode inversion (right).

complexity; therefore, it is in general more difficult to generate structures that satisfy the conditions set forth by the BHZ effective Hamiltonian.

IV. NUMERICAL RESULTS

A. C_{4v} and C_{2v} unit cells

We first discuss results for C_{4v} symmetric unit cells in Fig. 4(a), where the middle panel shows the unit cell exhibiting double Dirac cones with linear dispersion in the neighborhood of the degeneracy at a normalized frequency $\Omega = 1.295$. Here, the two p -like modes are degenerate and deterministic, while the two d -like modes are accidentally degenerate. The left panel in Fig. 4(a) shows the unit cell for which a complete band gap is opened, lifting the accidental degeneracy between the p - and d -like modes, while the right panel in Fig. 4(a) shows the unit cell after optimization inducing inversion of the modes in the left panel. The mode inversion process brings the p -like modes to the lower edge of the band gap, while the d -like modes are brought to the upper edge of the band gap. The complete band gaps within these two complementary unit cells are centered at the frequency of the original double Dirac cones with upper edge at $\Omega = 1.239$ and lower edge at $\Omega = 1.351$, resulting in an 8.65% relative band-gap size.

The results of the optimization process for the C_{2v} unit cell are shown in Fig. 4(b). The topologies for the C_{2v} unit cell are quite similar to the C_{4v} unit cells in Fig. 4(a), where slight variations of the geometry along the orthogonal directions can be found that demonstrate that the unit cells belong to the C_{2v} symmetry group. In this case, both the p - and d -like modes are accidentally degenerate at either the double Dirac cone or the edges of the topological band gap, where the user-defined degenerate frequencies are set to be the same as the ones in the C_{4v} cases. One difference compared to the C_{4v} results is that in opening the band gap in the left panel of Fig. 4(b), the optimization brings the degenerate p -like modes to the lower edge of the band gap while the d -like modes degenerate at the upper edge of the band gap. Mode inversion inverts the position of the p - and d -like modes as shown in the right panel of Fig. 4(b). For both the C_{4v} and C_{2v} unit cells, we have verified through calculation of Chern numbers that the unit cells which have quadrupolar d -like modes at the lower edge of the topological band gap are topologically nontrivial [55], while the mode-inverted counterpart is topologically trivial.

We verified the existence of opposite pseudospin states by examining the eigenspectral properties of a supercell, which consists of a topologically nontrivial unit cell interfacing with a topologically trivial unit cell, where for consistency the nontrivial unit cells were always below the interface. As shown by

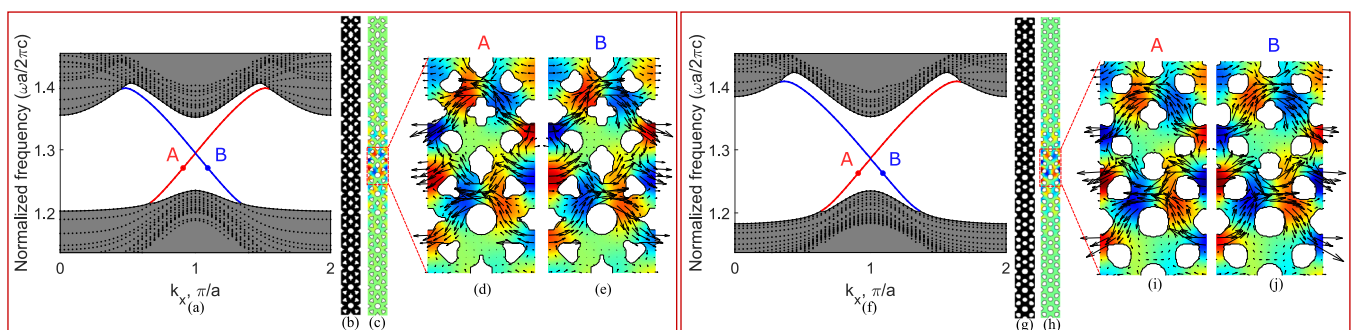


FIG. 5. Band-structure calculations for supercell constructed from (left) C_{4v} and (right) C_{2v} unit cells. (a), (f) Supercell band structure, where the dispersion of the opposite pseudospin states are colored red and blue. The bulk bands are colored in gray. (b), (g) Supercell. (c), (h) mode localization calculated at points A and B . (d), (e), (i), (j) Poynting vectors of the pseudospin states.

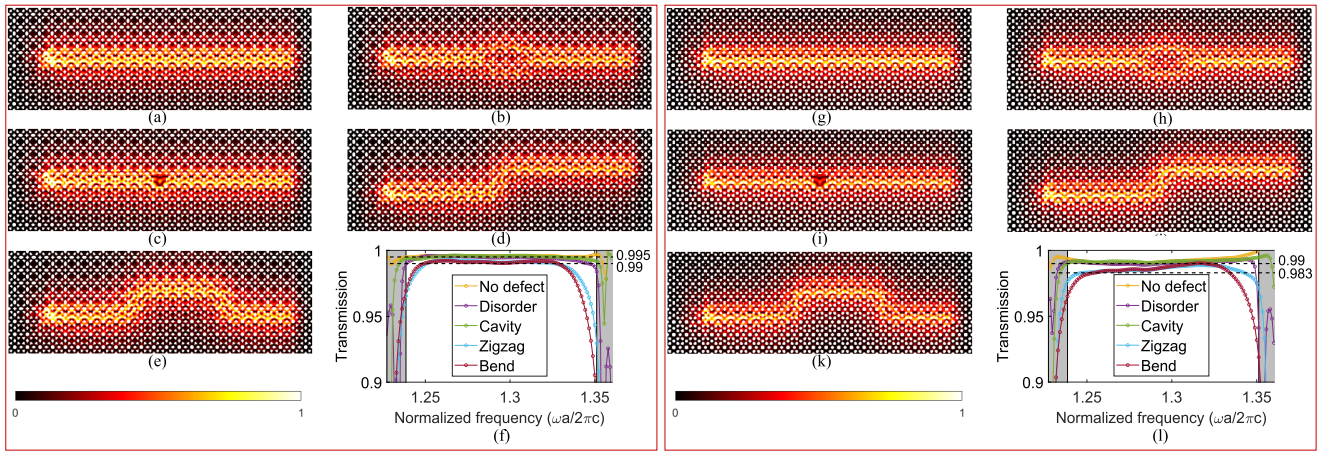


FIG. 6. One-way wave propagation simulation and transmission calculation for TI constructed from (left) C_{4v} and (right) C_{2v} unit cells. (a), (g) Defect free. (b), (h) Disorder. (c), (i) Defect. (d), (j) Zigzag bend. (e), (k) Double bend. (f), (l) Normalized energy transmission.

the left panel of Fig. 5, the C_{4v} supercell shows two opposite spin states crossing the band centered at the degenerate frequency of the double Dirac cones, with a complete bulk band gap matching the design frequencies. There exists a small edge state gap of 0.48% of the topological band gap, which is caused by the symmetry breaking at the interface [56,57]. It is shown in Fig. 5(c) that the displacement is localized within one unit cell above and below the interface. The Poynting vector calculations in Figs. 5(d) and 5(e) show the energy propagation in opposite directions for the two pseudospin states for the C_{4v} case, while similar pseudospin behavior is observed in Figs. 5(i) and 5(j) for the C_{2v} case. Because the double Dirac degeneracy for the C_{2v} case originates from two accidental degeneracies, there is a slightly larger edge-state gap of 0.98% of the total band gap.

Finally, we demonstrate in Fig. 6 the topologically protected interfacial wave propagation by presenting a series of one-way wave propagation simulations within the TIs constructed by the designs shown previously. The simulation domain is surrounded by two layers of unit cells working as crystalline perfectly matched layers (PMLs) to minimize scattering at the boundaries. The normalized transmission is measured by comparing the averaged energy flux at the input and output regions of the simulation domain, and is

measured within three unit cells above and below the interface, respectively. The simulations are conducted at $\Omega = 1.3174$, which is slightly above the pseudospin crossing frequency. The results show that the TIs constructed by optimized C_{4v} and C_{2v} unit cells are immune to defects such as disordered unit cells, cavity, zigzag bend, and double bend. For the C_{4v} cases, the transmission is greater than 0.99 for all cases for the majority of the topological band gap. For the C_{2v} cases, the transmission is greater than 0.983 for all cases, again showing robustness to disorder and defects. For the zigzag and double bend cases, the transmission dips slightly at the edges of the band gap in Figs. 4(a) and 4(b), though for the largest drop in transmission to 0.9, this translates into only a $10 \log_{10} 0.9 = -0.458$ dB loss.

B. C_4 and C_2 unit cells

The supercell band structures and edge states for C_4 and C_2 unit cells are shown in Fig. 7, where opposite spin states cross the band gap, with a complete bulk band gap matching the design frequencies as in Figs. 7(a) and 7(f). There exists a small edge-state gap of 3.7% of the topological band gap in the C_4 supercell, and we also found a similar edge-state gap of 2.9% in the C_2 supercell. It is shown in both

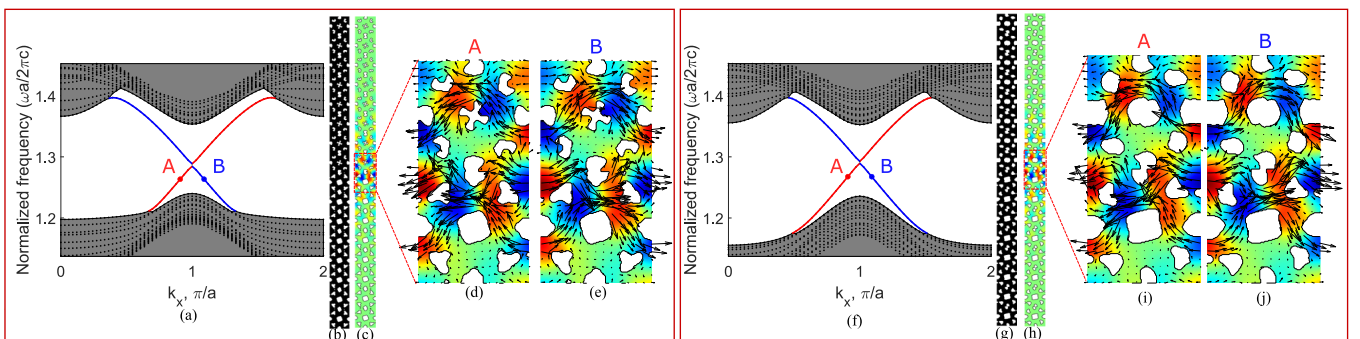


FIG. 7. Band-structure calculations for supercell constructed from (left) C_4 and (right) C_2 unit cells. (a), (f) Supercell band structure, where the dispersion of the opposite pseudospin states are colored red and blue. The bulk bands are colored in gray. (b), (g) Supercell. (c), (h) Mode localization calculated at points A and B. (d), (e), (i), (j) Poynting vectors of the pseudospin states.

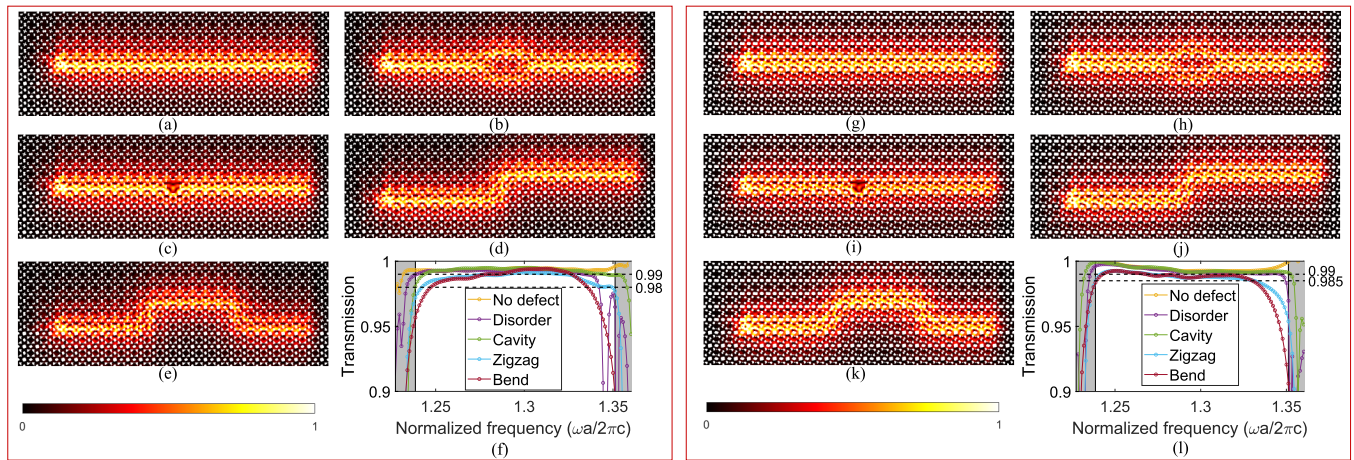


FIG. 8. One-way wave propagation simulation and transmission calculation for TI constructed from (left) C_4 and (right) C_2 unit cells. (a), (g) Defect free. (b), (h) Disorder. (c), (i) Defect. (d), (j) Zigzag bend. (e), (k) Double bend. (f), (l) Normalized energy transmission.

panels of Fig. 7 that the displacement localizes within one unit cell above and below the interface, and the energy propagates in opposite directions for the pseudospins in different states.

Finally, the one-way wave propagation simulation and transmission results for C_4 and C_2 unit cells are shown in Fig. 8. The one-way wave propagation simulation is again done at $\Omega = 1.3174$. It is seen that the TIs constructed by C_4 and C_2 unit cells can resist defects such as disorder, cavity, zigzag bend, and double bend. However, due to the existence of the small edge-state gap, the transmission of zigzag and double bend cases in C_4 falls below 99%, below the frequency where the small gap occurs, and there is a sharp transmission drop for the disorder case near the upper edge of the topological band gap. For the C_2 unit cell, the transmission is consistently above 98.5% for the majority of the gap.

V. CONCLUSION

In conclusion, we report the systematic design of double Dirac cones and topologically nontrivial phonons based on the QSHE for continuous, square symmetric unit cells by a gradient-based multiobjective topology optimization approach. The objective functions are judiciously formulated to mimic the eigenmode behaviors of the BHZ effective

Hamiltonian, such that the resulting optimized designs exhibit mode degeneracies at user-defined frequencies along with matched group velocities, and topologically complementary unit cells that exhibit mode inversion. Supercell band-structure calculations show that the one-way propagating edge modes span the topological band gap for both C_{4v} and C_{2v} cases, leading to robust, defect-immune, and backscattering-resistant TIs, where the pseudospin states are formed entirely or in part by accidental degeneracies through the topology optimization approach. While these results thus open the possibility for realizing QSHE-based pseudospin-dependent transport beyond hexagonal lattices, significant future work remains to elucidate any novel physical behavior that may emerge in square unit cell-based phononic TIs. Finally, because of the universality of the BHZ model for describing the QSHE in photonics and acoustics, our effective Hamiltonian inspired optimization approach can be easily extended to these areas.

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